

Docket No.: 83028US1
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Richard L. Henry et al.

Application No.: 10/768,747

Confirmation No.: 7954

Filed: January 23, 2004

Art Unit: 2822

For: Technique for Perfecting the Active Regions of
Wide Bandgap Semiconductor Nitride Devices

Examiner: M. F. Guerrero

RESPONSE TO RESTRICTION REQUIREMENT

Customer Window, MS Amendment
U.S. Patent and Trademark Office
Randolph Building
401 Dulany Street
Alexandria, Virginia 22314

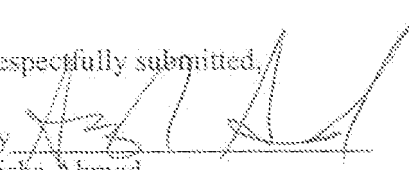
Dear Sir:

In response to the restriction requirement set forth in the Office Action mailed March 7, 2006, Applicant hereby provisionally elects claims 1-14 for continued examination.

The Examiner has required restriction between claims 1-14 drawn to a method of making semiconductor devices, and claims 15-20 drawn to a semiconductor device because the Examiner asserts these inventions are independent and distinct.

Dated:

Respectfully submitted,

By 
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